Tem perature dependent uorescence in disordered Frenkelchains: interplay of equilibration and local band-edge level structure

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W e m odel the optical dynam ics in linear Frenkel exciton system s governed by scattering on static disorder and lattice vibrations, and calculate the tem perature dependent uorescence spectrum and lifetime. The uorescence Stokes shift shows a nonmonotonic behavior with tem perature, which derives from the interplay of the local band-edge level structure and therm al equilibration. The model yields excellent ts to experiments perform ed on linear dye aggregates.

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Optical dynam ics and em ission of light in solid state system s are topics of considerable fundam ental and technological in portance. A variety of materials is currently studied as light em itting devices. E xam ples are sem iconductor quantum wells and wires [1], conjugated polymers [2], and molecular aggregates [3]. Closely related is the quest for understanding the optical dynam ics in photosynthetic antenna system s [4, 5]. The fundam ental understanding and description of the emission properties of all these systems are challenging, because they involve a complicated interplay of processes. The emission is usually caused by excitons and is particularly sensitive to the scattering of these quasi-particles on static disorder, which may lead to their localization, and lattice vibrations. The latter results in vibronic relaxation and hopping of the excitation between (localized) exciton states, which gives rise to spatial and spectral di usion. These di usion processes compete with spontaneous emission and nonradiative loss. Depending on the details of this com petition, the excitons m ay or m ay not reach therm al equilibrium before em ission occurs. Tem perature plays an important role in this competition. The therm aldestruction of cooperative em ission in molecular aggregates [6], quantum wells [7], and quantum wires [8, 9] is a wellknown example of an interesting tem perature dependent e ect. The Stokes shift of the exciton uorescence may exhibit interesting therm albehavior as well [10, 11].

In this Letter, we theoretically study the exciton dynam ics and the resulting emission properties of linear chains carrying small-radius excitons. We account for both exciton localization by static disorder and scattering of the excitons on lattice vibrations. The interplay of nonequilibrium conditions and the local band-edge level structure of disordered chains leads to interesting e ects in the emission. A comparison to experiment is made. Frenkel exciton Ham iltonian

$$H = \begin{cases} X^{N} & X^{N} \\ n \text{ jihn } j + & J_{nm} \text{ jihn } j; \end{cases} (1)$$

where $_n$ is the excitation energy of the nth m olecule and jni denotes the state in which m olecule n is excited and all others are in their respective ground states. In order to m odel the e ect of random solvent shifts, the $_n$ are assumed to be mutually uncorrelated G aussian stochastic variables with m ean $_0$ and standard deviation . The hopping integrals J_{nm} are nonrandom and originate from dipolar coupling: $J_{nm} = J = j_n m j^3$, $J_{nn} = 0$. Here, J is positive, in plying that the optically allowed exciton states reside at the bottom of the exciton band.

W e will assume that the coupling of the excitons to lattice vibrations is weak. It is then appropriate to use a basis of eigenstates of H . This basis consists of N exciton states, which are labeled by = 1; ...; N. The energy of the thexciton, E , is the theigenvalue of the N $\,$ N matrix H_{nm} = hn H jm i, while the nth component of the corresponding eigenvector, ' n, gives the man plitude of the thexciton state on molecule n: ji= n=1'njni. The disorder leads to localization of the eigenstates and gives rise to a tail in the density of states (DOS) below the bare band edge [12, 13]. This tail is of particular interest for optical properties, as the states residing in it carry most of the oscillator strength, $F = j_n' n_j^2$. W hile the DOS accumulated over the entire chain is a smooth function of energy, locally it exhibits structure [14]. This local level structure is of key in portance to the low-tem perature dynam ics and is described below.

The exciton states in the tail of the DOS are localized on nite segments, which near the band edge have a typical size N (see Fig. 1). Within its own segment, each one of these states is the low est-energy eigenstate. They have wave functions without nodes in the segments and carry an oscillator strength F N. Their spontaneous emission rates, = $_0F$ (with $_0$ the emission rate of a single molecule), thus scale like N. This is referred

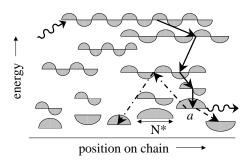


FIG.1: Schem atic picture of the localized exciton wave functions near the lower band edge in a disordered linear chain. A lso indicated are the optical pumping and emission processes (wavy arrows) and various intraband relaxation processes (dashed and dash-dotted arrows).

to as superradiant enhancement [6]. Bottom states on neighboring segments have small overlap. Offen a second, higher-energy, exciton state may be distinguished on a segment, separated from the bottom state by an energy of the order of 3 2 J=N 2 , as is dictated by energy quantization. These states have one node within the segments and small oscillator strengths. Still higher local states are usually delocalized over two orm ore segments and carry negligible oscillator strengths. The local level structure is washed out in the average over the entire chain due to the fact that the distribution of energies of the bottom segment states also has a width of the order of 3 2 J=N 2 [14].

W eak exciton-phonon coupling leads to scattering between the exciton eigenstates. To describe this dynam ics, we will use the Paulim aster equation for the populations, P (t), of the localized exciton states:

$$P = R$$
 (t) $P + (W P W P)$: (2)
= 1

Here, the dot denotes the time derivative, R (t) is the optical pumping rate, is the above de ned spontaneous emission rate, and W is the transition rate from the localized state to the state induced by the exciton-phonon scattering. For the latter, we will use

$$W = W_0 S (E E) G (E E) {X^{N} \atop n=1} , {2 \atop n'} , {2 \atop n'} ; (3)$$

where the constant W $_0$ characterizes the scattering, the sum over sites is the overlap integral of exciton probabilities for the states and , and S (E E) describes that part of the \pm E jdependence of W that derives from the energy dependence of the exciton-phonon coupling constant and the phonon density of states. Finally, G (E) = n (E) if E > 0 and G (E) = 1 + n (E) if E < 0, with n () = [exp(=k_BT) 1]^1 the mean occupation number of a phonon state with the energy . Equation (3), which meets the principle of detailed balance, is the

generic result from st-order perturbation theory in the exciton-phonon interaction [15, 16, 17].

We have numerically simulated the above model of intra-band exciton dynamics for scattering on accustic phonons of the chains' host medium. We have set $S = \frac{1}{F}$ E $\frac{1}{F}J$, which properly accounts for a decrease of the coupling of excitons to acoustic phonons at small wave vectors and prevents the divergence of W at small energy di erences. We will illustrate the salient results of our model by using parameters that are relevant to molecular aggregates of the dye THIATS: $_0 = 18138$ cm¹, J = 740 cm¹, and $_0 = (2=31)$ 10⁸ s¹ [11, 18]. These parameters are xed; the two free parameters are

and W $_{\rm 0}$, for which we will use the values that yield the best t to experimental data: = 0.23J and $W_0 = 30J$, respectively (vide infra). A more elaborate analysis of ourm odel, covering a wider range of values for and W_{0} , will be discussed elsewhere [19]. The motivation to focus on the example of THIATS aggregates, is that a large num ber oftem perature dependent spectroscopic data are known for these systems [11, 20]. W e will lim it our attention to tem peratures sm all com pared to the D avydov splitting of 3000 cm⁻¹ that exists for these aggregates between the so-called J band at the lower exciton band edge and the so-called H band at the upper band edge [11, 18]. For these tem peratures our e ective m odel with one molecule per unit cell may be used [21]. We have used a chain size of N = 500 in our simulations, which far exceeds the typical band-edge exciton size N = 30 for = 0:23J.

W e will rst address the absorption and steady-state em ission spectra, which are calculated through

A (E) =
$$\frac{1}{N} \stackrel{D X^{N}}{=} (E E);$$
 (4a)

$$I^{st}(E) = \frac{1}{N}^{D} X$$
 $P^{st}(E E);$ (4b)

respectively. Here, the angular brackets denote the average over the disorder realizations. Furtherm ore, Pst is the steady-state solution of the master equation Eq. (2) with the source term given by R (t) = F if E falls inside a narrow window in the blue wing of the J band and R = 0 otherwise. This blue-tail excitation condition agrees with common experimental conditions.

The spectra calculated for T = 10 K are shown by solid lines in Fig. 2, together with the J band and uorescence spectrum measured for THIATS aggregates at the same temperature (dots) [11]. C learly, both experimental spectra are tted very wellwithin ourmodel. The main deviations occur in the tails, which are quite sensitive to the precise nature of the disorder (diagonal versus o -diagonal disorder, no perfect alignment of molecular dipoles). We note that the uorescence band is shifted

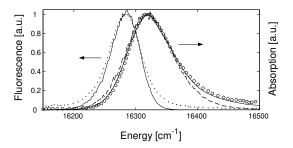


FIG.2: Calculated absorption and uorescence spectra (solid lines) at 10 K for the model parameters described in the text, compared to the J band () and uorescence spectrum () for THIATS aggregates measured at T = 10 K [11]. The dashed line is the uorescence spectrum calculated for the same parameter set, except that now W $_0 = 10^{-3}$ J.

to the red (Stokes shift) and narrowed with respect to the J band. K eeping in m ind that the absorption band is dom inated by the set of superradiant bottom states of the various localization segments on the chain, this is an indication that after the fast initial relaxation to a particular bottom state (e.g., the levela in Fig.1), the excitons have a chance to relax to even low er states. This is a signature of migration to other localization segments, a process which at low tem peratures is hindered by the sm all overlap between exciton wave functions of di erent segments. The fact that, in spite of this, m igration m ay occur before radiative em ission takes place, is due to the large value of W₀, which brings the system into a regime that we refer to as the fast-intersegm ent-relaxation lim it. To illustrate the role of W $_0$, we also present in Fig. 2 (dashed line) the simulated uorescence spectrum for W $_0 = 10^{-3}$ J (all other param eters as above). In this slow-relaxation lim it the uorescence spectrum closely follows the absorption band and no Stokes shift occurs.

At zero tem perature, the possibility for the excitation to m igrate to other localization segments, after the initial relaxation process, is very small. The reason is that the m igration m ay then only occur via a jump to a lower exciton state on a neighboring segment, for which at least som e (albeit sm all) wave function overlap exists (cf. the process denoted by the dashed arrow in Fig. 1). However, the probability of nding a lower exciton state on a neighboring segment is small, because the initial state already lies in the tail of the DOS. Therefore, in practice, low-tem perature exciton m igration is lim ited to at m ost one jump. As a consequence of this blockade for di usion, there is not much opportunity for the excitation to explore the fullD OS during its lifetim e and to equilibrate to the lowest state on the disordered chain. Thus, even for large W 0, the zero tem perature Stokes shift is lim ited to values of the order of the J band width.

Upon increasing the temperature, higher states may therm ally be excited and one expects the Stokes shift to decrease and eventually vanish. This is the generic be-

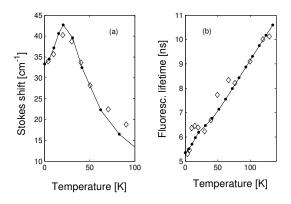


FIG.3: (a) Calculated Stokes shift of the uorescence spectrum as a function of temperature for the parameter set described in the text (). The solid line is a guide to the eye. D iam onds mark the measured Stokes shift for THIATS aggregates reported in Ref. [11]. (b) As in (a), for the uorescence lifetime instead of the Stokes shift. D iam onds are the experimental data from Ref. [20].

havior for single molecules. Our simulations show that at elevated temperatures this also occurs for the exciton system (Fig. 3(a)). However, our results also reveal a counter-intuitive interm ediate regime, where the Stokes shift increases with tem perature. This nonm onotonic behavior is intimately related to the interplay of equilibration and the local level structure near the exciton band edge. Upon slightly increasing the tem perature from zero, a sm all fraction of the population is therm ally raised from the bottom state of a segment to a higher exciton state that overlaps with the same segment. As this higher state generally overlaps with m ore segments, this provides a m eans of distributing the population over two or more neighboring segments. The total process is denoted by the dash-dotted arrows in Fig. 1. This overlap-assisted activated m igration is slow, but it allows the excitation to probe more segments for a low-energy position and circum vents to som e extent the blockade for m igration which occurs at T = 0 K. Hence, the excitons get closer to therm al equilibrium, which at low tem peratures leads to a larger Stokes shift. Such anom alous low-tem perature behavior has also been predicted and observed for W annier excitons m igrating between local potentialm in in a in narrow quantum wells [10].

As we also see in Fig. 3(a), our num erical results, obtained for the same parameter set as was used to t the low-tem perature spectra, agree very wellw ith the experimental data for T H IATS aggregates reported in Ref. [11]. This gives strong evidence for the validity of our dynamic model and the concept of overlap-assisted therm ally-activated intersegment hopping. U sing the typical local level separation 3 2 J=N 2 and the superradiant emission rate N $_{0}$, it may be shown that the tem perature interval overwhich the Stokes shift behaves in an anom alous way (i.e., increases with T) scales roughly linearly

with the absorption line width and only weakly (inverse logarithm ically) depends on the ratio $W_0 = 0$ [19].

We nally turn to the lifetime of the total uorescence intensity after pulsed excitation. For the generally nonexponential intensity trace I (t) = h P- (t)i, we dene the lifetime as its rst moment, i.e. Rthe expectation value of the photon emission time: $= {}_{0}^{1}$ h P (t) idt [17]. Here, P (t) is the solution of Eq. (2) with R (t) = cF (t) if E falls in a narrow window in the blue tail of the absorption band and R (t) = 0 otherwise. The norm alization constant c is such that directly following the excitation pulse the total population on the chain,

P, equals unity.

The generic behavior of the lifetime as a function of tem perature is well known. At low T, the decay is dom inated by the superradiant bottom states of the localization segments, leading to a uorescence lifetime of the orderof1=N $_0$.W ith increasing T, the exciton population is shared by the superradiant states as well as an increasing num ber of higher-lying dark states. This leads to an increase of the uorescence lifetime, as has been observed for various exciton system s [6, 7, 8, 9, 20, 22]. For TH I-ATS aggregates the lifetime shows a nearly linear tem perature dependence from 0 to 130 K [20] (see Fig. 3 (b), diam onds). For BIC aggregates a sim ilar linear increase was observed and, based on the at nature of the DOS for ideal two-dimensional systems, this was put forward as evidence for a two-dimensional structure of these aggregates [22]. It turns out, how ever, that the interplay of the (local) DOS and equilibration in our one-dimensional model with disorder may equally well explain the quasilinear behavior. The solid line in Fig. 3(b) gives our simulated results, obtained for the same parameters that were used to t the low-tem perature spectra of THIATS. W e conclude that the model, without any new parameters, yields an excellent t to the experim ental data. W e also m ention that at sm all W_0 (slow relaxation), the linear tem perature dependence m ay be preceded by a low tem perature plateau [19], which is the type of behavior that is observed for aggregates of pseudo-isocyanine [6].

In sum m ary, we have analyzed the tem perature dependence of the uorescence in one-dimensional disordered exciton system s and obtained excellent ts to experim entaldata for aggregates of the THIATS dye molecules. As far as we are aware, this is the rstm odel calculation that yields such good agreem ent with a variety of uprescence experim ents on linear dye aggregates. P revious calculations focused only on the tem perature dependent lifetim e and did not account for exciton localization by disorder [23]. Our approach, based on the master equation with perturbatively calculated rates W , is consistent as long as the rates for scattering between the optically dom inant states do not exceed their energy separation. For the param eters used for THIATS we nd that, in spite of the seem ingly large value of W 0, at low tem perature this criterion is just obeyed, due to the small overlap integral $P_{n=1}^{N}$, $P_{n'n}^{2}$, 1=N for the exciton wave functions near the band edge. W ith increasing temperature, the scattering rates increase and around 100 K they lead to a visible contribution to the absorption line width (hom ogeneous broadening) [11]. At such high temperatures the m aster equation description breaks down and the full exciton density m atrix m ust be considered instead [4].

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